



APX823/APX824/APX825A

PROCESSOR SUPERVISORY CIRCUITS

Description

The APX823/APX824/APX825A family of supervisors provides circuit initialization and timing supervision, primarily for DSP and processorbased systems.

During power-on, RESET is asserted when supply voltage V_{CC} becomes higher than 1.1V. Thereafter, the supply voltage supervisor monitors V_{CC} and keeps RESET active as long as V_{CC} remains below the threshold voltage \underline{V}_{TH} . An internal timer delays the return of the output to the inactive state (high) to ensure proper system reset. The delay time, t_d starts after V_{CC} has risen above the threshold voltage V_{TH}. When the supply voltage drops below the threshold voltage V_{TH}. When the supply voltage drops below the threshold voltage V_{TH}. When the supply voltage drops below the threshold voltage V_{TH}. Be output becomes active (low) again. No external components are required. All the devices of this family have a fixed-sense threshold voltage V_{TH}.

The APX823/APX825A devices incorporate a manual reset input, \overline{MR} . A low level at \overline{MR} causes \overline{RESET} to become active. The APX824/APX825A devices include a high-level output RESET. APX823/APX824/APX825A have a watchdog timer that is periodically triggered by a positive or negative transition at WDI. When the supervising system fails to retrigger the watchdog circuit within the time-out interval, ttout, \overline{RESET} becomes active for the time period td. This event also reinitializes the watchdog timer. Leaving WDI unconnected disables the watchdog.

In applications where the input to the WDI pin may be active (transitioning high and low) when the APX823/APX824/APX825A asserting $\overrightarrow{\text{RESET}}$ the APX823/APX824/APX825A does not return to a non-reset state when the input voltage is above Vt. The product spectrum is designed for supply voltage of 2.5V, 3V, 3.3V and 5V. The circuits are available in a SOT25 and SOT26 packages. The APX823/APX824/APX825A devices are characterized for operation over a temperature range of -40°C to 105°C.

Features

- Power-on reset generator with fixed delay time of 200ms Typ
- Manual reset input (APX823/APX825A)
 Reset output available in active-low
- (APX823/APX824/APX825A), active-high (APX824/APX825A)
- Supply voltage supervision range 2.5V, 3V, 3.3V, 5V
- Watchdog timer
- Supply current of 30µA (Typ.)
- Temperature range: -40°C to 85°C
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/productdefinitions/</u>

Pin Assignments



Applications

- Applications using DSPs, microcontrollers, or microprocessors
- Industrial equipment
- Programmable controls
- Portable/battery-powered equipment
- Intelligent instruments
- Wireless communications systems
- Notebook/desktop computers

- Notes: 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
 - 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 - 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.



APX823/APX824/APX825A

Typical Application Circuit



Pin Descriptions

Pin Name	Description
GND	Ground
RESET	Reset output pin
(RESET)	
V _{CC}	Operating voltage input
WDI	Watchdog input
MR	Manual reset

Functional Block Diagram





Symbol		Rating	Unit		
ESD HBM	Human Body Model ESD	Protection		5	KV
ESD MM	Machine Model ESD Prote	ection		200	V
V _{CC}	Supply Voltage			6.0	V
V _{RESET}	RESET, RESET, MR, V	VDI		-0.3 to (V _{CC} +0.3)	V
I _{CC}	Input Current V _{CC}			20	mA
Ι _Ο	Maximum High Output Cu	rrent		20	mA
		Derating Factor Above	SOT25	6.2	m)///9C
		$T_A = 25^{\circ}C$	SOT26	5.8	mW/°C
		$T_A = 25^{\circ}C$ Power Rating	SOT25	500	m)//
PD	Continuous Total Power	T _A = 25 C Power Raing	SOT26	470	mW
гD	Dissipation	$T_A = 70^{\circ}C$ Power Rating	SOT25	220	mW
		$T_A = 70$ C Power Rating	SOT26	210	TIIVV
		$T_A = 85^{\circ}C$ Power Rating	SOT25	125	mW
			SOT26	120	11177
T _{OP}	Operating Junction Temperature Range			-40 to 105	°C
T _{ST}	Storage Temperature Ran	Storage Temperature Range			°C

Absolute Maximum Ratings (Over operating ambient temperature range, unless otherwise noted)*

* Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

Recommended Operating Conditions

Symbol	Parameter	Min	Max	Unit
V _{CC}	Supply Voltage	1.1	5.5	V
V _{IN}	Input Voltage	0	(V _{CC} +0.3)	V
VIH	High-level Input Voltage at \overline{MR} and WDI	$0.7 \times V_{CC}$	-	V
VIL	Low-level Voltage	-	$0.3 \times V_{CC}$	V
Δt/ΔV	Input Transition Rise and Fall Rate at \overline{MR} or WDI	-	100	ns/V
T _A	T _A Operating Ambient Temperature Range		85	°C
T _R	V_{CC} Rising Time ($V_{CC} = 0 \sim VT$)	-	100	V/ uS



Symbol		Pa	rameter	Test Conditions	Min	Тур.	Max	Unit
			APX823/APX824/APX825A - 29/26/23	V _{CC} = <u>V_{TH}</u> +0.2V I _{OH} =-20µA	-0.8×V _{CC}			v
		RESET	APX823/APX824/APX825A - 40/31	V _{CC} = <u>V_{TH-}</u> +0.2V I _{OH} =-30µA	0.8 × 0.00	-	-	V
V _{OH}	High-level Output Voltage		APX823/APX824/APX825A 46/44	V _{CC} = <u>V_{TH}</u> .+0.2V I _{OH} =-120μA	V _{CC} -1.5V	-	-	V
		RESET	APX824/APX825A -29/26/23	V _{CC} <u>></u> 1.8V, I _{OH} = -100µA	0.8×V _{CC}	_	_	v
		REGET	APX824/APX825A - 46/44/40/31	V _{CC} <u>></u> 1.8V, I _{OH} = -150µA	0.0 × VCC		_	Ň
			APX824/APX825A -29/26/23	V _{CC} = <u>V_{TH}</u> .+0.2V I _{OL} =1mA				
		RESET	APX824/APX825A -40/31	V _{CC} = <u>V_{TH}</u> .+0.2V I _{OL} =1.2mA	-	-	0.4	V
V	Low-level	ow-level	APX824/APX825A -46/44	V _{CC} = <u>V_{TH}</u> .+0.2V I _{OL} =3mA				
V _{OL}	VOL Output Voltage		APX823/APX824/APX825A - 29/26/23	V _{CC} = <u>V_{TH}</u> -0.2V I _{OL} =1mA				
	RESET	APX823/APX824/APX825A - 40/31	V _{CC} = <u>V_{TH-}-0.2V</u> I _{OL} =1.2mA	-	-	0.4	V	
		APX823/APX824/APX825A - 46/44	V _{CC} = <u>V_{TH}</u> 0.2V I _{OL} =3mA					
V _{RESET}	Power-up Reset	Voltage (Note 4)	V _{CC ≥} 1.1V, I _{OL} =20µA	-	-	0.4	V
		APX	823/APX824/APX825A -23		2.21	2.25	2.30	
		APX	823/APX824/APX825A -26		2.59	2.63	2.69	
		APX	823/APX824/APX825A -29		2.88	2.93	3.00	
		APX	823/APX824/APX825A -31	$T_A = 0^{\circ}C - 85^{\circ}C$	3.02	3.08	3.15	V
		APX	823/APX824/APX825A -40		3.93	4.00	4.08	
	Negative-going	APX	823/APX824/APX825A -44		4.31	4.38	4.47	
V _{TH-}	Input Threshold	APX	823/APX824/APX825A -46		4.56	4.63	4.72	
v IH-	Voltage	APX	823/APX824/APX825A -23		2.15	2.25	2.34	
	(Note 5)	APX	823/APX824/APX825A -26		2.51	2.63	2.74	I
		APX	823/APX824/APX825A -29		2.80	2.93	3.05	
		APX	823/APX824/APX825A -31	T_{A} = -40°C -85°C	2.94	3.08	3.20	V
		APX	823/APX824/APX825A -40		3.82	4.00	4.16	
		APX	823/APX824/APX825A -44		4.19	4.38	4.56	
		APX	823/APX824/APX825A -46		4.43	4.63	4.82	

Electrical Characteristics (Over recommended operating ambient temperature range, unless otherwise noted)

Notes: 4. The lowest supply voltage at which RESET becomes active. T_R , V_{CC} \ge 15µs/V.

5. To ensure best stability of the threshold voltage, a bypass capacitor (ceramic, 0.1µF) should be placed near the supply terminals.



Electrical Characteristics (continued)

Symbol		Parameter	Test Conditions	Min	Тур.	Max	Unit
		APX823/APX824/APX825A -23					
		APX823/APX824/APX825A -26		-	50	_	
	Hysteresis at V _{CC}	APX823/APX824/APX825A -29			00		
V _{hys}	Input	APX823/APX824/APX825A -31					mV
	niput	APX823/APX824/APX825A -40	_				
		APX823/APX824/APX825A -44		-	50	-	
		APX823/APX824/APX825A -46					
Τ _S	Set-up Time	$V_{CC} = V_{TH}$ to ($V_{TH} - 100$ mV)			20		μs
	Average High-		WDI=V _{CC} ,				
I _{IH(AV)}	level Input		Time average	-	120	-	μA
	Current	WDI	(dc=88%)				
	Average Low-		WDI=0.3V,				
I _{IL(AV)}	level Input		V _{CC} =5.5V time	-	-15	-	μA
	Current		average (dc=12%)				
I _{IH}	High-level Input Current	WDI	WDI=V _{CC}	-	120	160	μA
۱ _{۱L}	Low-level Input	WDI	WDI=0.3V,	-	120	160	μA
	Current		V _{CC} =5.5V				
		WDI and MR					
ICC	Supply Current	Unconnected, Outputs unconnected	$V_{CC} = \underline{V_{TH}} + 0.2V$	-	30	40	μΑ
	Internal Pull-up Re	esistor at MR		-	60	-	kΩ
тс	V _{OUT} Temperature Coefficient				50	-	ppm/°C
Ci	Input Capacitance at MR , WDI		$V_1 = 0V$ to 5.5V	-	5	-	pF
Δ.,	Thormal Posiston	ce Junction-to-Ambient	SOT25 (Note 6)		161		°C/W
θ_{JA}	riterinar Kesistano		SOT26 (Note 6)		169		0/00
Δ	Thormal Desistant	ce Junction-to-Case	SOT25 (Note 6)		27		°C/W
θ_{JC}	Thermal Resistant	ce Junction-to-Case	SOT26 (Note 6)		28		C/VV

Note: 6. Test condition for SOT25 and SOT26: Devices mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.



Timing Requirements (@ $R_L = 1m\Omega$, $C_L = 50pF$, $T_A = 25^{\circ}C$)

Symbol	Parameter		Test Conditions		Тур.	Max	Unit
t _W	Pulse Width	at MR	$V_{CC} \ge \underline{V_{TH}} + 0.2V, \underline{V_{II}} = 0.3 \times V_{CC}, \underline{V_{IH}} = 0.7 \times \underline{V_{CC}}$	<u>100</u>	-	-	<u>ns</u>
ι _{νν}		at <u>WDI</u>	$V_{CC\geq} \underline{V}_{\underline{TH}} + 0.2V, V_{IL} = 0.3 \times V_{CC}, V_{IH} = 0.7 \times V_{CC}$	<u>50</u>	-	-	ns

Switching Characteristics (@ $R_L = 1m\Omega$, $C_L = 50pF$, $T_A = 25^{\circ}C$)

Symbol	P	Parameter	Test Conditions	Min	Тур.	Max	Unit
<u>t_{tout}</u>	Watchdo <u>g Time Out</u>	APX823/APX824/APX825A	V _{CC≥} <u>V_{TH}</u> -+0.2V, See timing diagram	<u>1.12</u>	1.6	<u>2.4</u>	s
t _d	Delay Time	APX823/APX824/APX825A	V _{CC≥} <u>V_{TH-}</u> +0.2V, See timing diagram	140	200	280	ms
t _{PHL}	Propagation (Delay) Time, High-to-low-level	MR to RESET delay (APX823/APX825A)	V _{CC} > <u>V_{TH}</u> .+0.2V, V _{IL} =0.3 × V _{CC} , V _{IH} =0.7 × V _{CC}	-	-	0.1	μs
	Output	V _{CC} to RESET delay	V _{IL} = <u>V_{TH}</u> 0.2V, V _{IH} = <u>V_{TH}</u> .+0.2V	-	-	25	μs
t _{PLH}	Propagation (Delay) Time, Low-to-high-level	MR to RESET delay (APX824/APX825A)	$V_{CC} > \underline{V_{TH}}.+0.2V,$ $V_{IL}=0.3 \times V_{CC},$ $V_{IH}=0.7 \times V_{CC}$	-	-	0.1	μs
	Output	V _{CC} to RESET delay (APX824/APX825A)	V _{IL} = <u>V_{TH}</u> 0.2V, V _{IH} = <u>V_{TH}</u> .+0.2V	-	-	25	μs



Timing Diagram









Typical Characteristics











Ordering Information



		Baakaga		Packing	
Orderable Part Number	Package Code	Package (Note 7)	Quantity	Carrier	Part Number Suffix
APX823-XXW5G-7	W5	SOT25	3,000	7" Tape & Reel	-7
APX824-XXW5G-7	W5	SOT25	3,000	7" Tape & Reel	-7
APX825A-XXW6G-7	W6	SOT26	3,000	7" Tape & Reel	-7

Note: 7. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



Marking Information

(1) SOT25



(2) SOT26



Marking Table

Device	Package	Identification Code
APX823-46W5	SOT25	W1
APX823-44W5	SOT25	W2
APX823-40W5	SOT25	W3
APX823-31W5	SOT25	W4
APX823-29W5	SOT25	W5
APX823-26W5	SOT25	W6
APX823-23W5	SOT25	W7
APX824-46W5	SOT25	T2
APX824-44W5	SOT25	Т3
APX824-40W5	SOT25	T4
APX824-31W5	SOT25	T5
APX824-29W5	SOT25	T6
APX824-26W5	SOT25	T7
APX824-23W5	SOT25	T8
APX825A-46W6	SOT26	Т9
APX825A-44W6	SOT26	TA
APX825A-40W6	SOT26	ТВ
APX825A-31W6	SOT26	TC
APX825A-29W6	SOT26	TD
APX825A-26W6	SOT26	TE
APX825A-23W6	SOT26	TF



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.



	SOT	F25				
Dim	Min	Max	Тур			
Α	0.35	0.50	0.38			
В	1.50	1.70	1.60			
С	2.70	3.00	2.80			
D	-	-	0.95			
Н	2.90	3.10	3.00			
J	0.013	0.10	0.05			
Κ	1.00	1.30	1.10			
L	0.35	0.55	0.40			
Μ	0.10	0.20	0.15			
Ν	0.70	0.80	0.75			
d	α 0° 8° -					
All D	imensi	ons in	mm			

SOT26



	SC	DT26	
Dim	Min	Max	Тур
A1	0.013	0.10	0.05
A2	1.00	1.30	1.10
A3	0.70	0.80	0.75
b	0.35	0.50	0.38
c	0.10	0.20	0.15
D	2.90	3.10	3.00
е	-	-	0.95
e1	-	-	1.90
Е	2.70	3.00	2.80
E1	1.50	1.70	1.60
L	0.35	0.55	0.40
а	-	-	8°
a1	-	-	7°
All	Dimen	sions	in mm

APX823/APX824/APX825A Document number: DS31323 Rev. 5 - 2 Downloaded from Arrow.com.



Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT25

Dimensions	Value
Z	3.20
G	1.60
Х	0.55
Y	0.80
C1	2.40
C2	0.95

SOT26



Dimensions	Value (in mm)
С	2.40
C1	0.95
G	1.60
Х	0.55
Ý	0.80
Y1	3.20

Mechanical Data

- Moisture Sensitivity:
 - SOT25 Level 3 per J-STD-020
 - SOT26 Level 3 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 😨
- Weight:
 - SOT25: 0.0153 grams (Approximate)
 - SOT26: 0.016 grams (Approximate)



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